



### Description

Thyristor AC controller module for mains frequency (50Hz/60Hz), utilizing two SCR dies in anti-parallel configuration for applications such as heating.

Robust SOT227B package with isolation voltage 2500V minimum


### Features & Benefits

- Compact and robust SOT227B package
- High current handling capability,  $I_{T(RMS)}=90A$
- Glass – passivated junctions
- Surge capability up to 950 A

### Applications

High power electrical tankless water heater

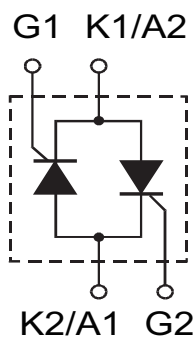
### Agency Approval

| Agency  | Agency File Number |
|---|--------------------|
|  | E71639             |

### Main Features

| Symbol            | Value | Unit |
|-------------------|-------|------|
| $I_{T(RMS)}$      | 90    | A    |
| $V_{DRM}/V_{RRM}$ | 600   | V    |
| $I_{GT}$          | 50    | mA   |

### Schematic Symbol



### Absolute Maximum Ratings

| Symbol       | Parameter  | Test Conditions   | Value      | Unit                   |
|--------------|--|---|------------|------------------------|
| $I_{T(RMS)}$ | On-State RMS Current - 360° as module                | $T_C = 92^\circ\text{C}$  | 90         | A                      |
|              | On-State RMS Current - 180° as single SCR            |   | 65         |                        |
| $I_{T(AV)}$  | Average On-State Current - 360° as module            | $T_C = 92^\circ\text{C}$  | 64         | A                      |
|              | Average On-State Current - 180° as single SCR        |   | 41         |                        |
| $I_{TSM}$    | Peak Non-Repetitive Surge Current, single cycle 60Hz |   | 950        | A                      |
| $I^2t$       | $I^2t$ Value for fusing                              | $t_p = 8.3\text{ms}$  | 3745       | $\text{A}^2\text{s}$   |
| $di/dt$      | Critical Rate-of-Rise of On-State Current            | $I_G = 150\text{mA}$ , $f=60\text{Hz}$ ,<br>$T_J = 125^\circ\text{C}$ | 200        | $\text{A}/\mu\text{s}$ |
| $P_{GM}$     | Peak Gate Power Dissipation                          | $T_J = 125^\circ\text{C}$ , $T_p=30\mu\text{s}$                       | 10         | W                      |
|              |  | $T_J = 125^\circ\text{C}$ , $T_p=300\mu\text{s}$                      | 5          |                        |
| $P_{G(AV)}$  | Average Gate Power Dissipation                       | $T_J = 125^\circ\text{C}$   | 1.0        | W                      |
| $T_{stg}$    | Storage Junction Temperature Range                   |   | -40 to 150 | $^\circ\text{C}$       |
| $T_J$        | Operating junction Temperature Range                 |   | -40 to 125 | $^\circ\text{C}$       |

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

| Symbol   | Parameter                                  | Test Conditions  | Value |      | Unit                   |
|----------|--|--|-------|------|------------------------|
|          |  |  | min.  | max. |                        |
| $I_{GT}$ | DC Gate Trigger Current                    | $V_D = 12\text{V}$ ; $R_L = 30\ \Omega$  | 5     | 50   | mA                     |
| $V_{GT}$ | DC Gate Trigger Voltage                    |  |       | 1.6  | V                      |
| $I_H$    | Holding Current                            | $I_T=400\text{mA}$ (initial)   |       | 80   | mA                     |
| $dv/dt$  | Critical Rate-of-Rise of Off-State Voltage | $T_J = 125^\circ\text{C}$ , $V_D = V_{DRM}/V_{RRM}$ ,<br>Exponential Waveform, Gate Open                   | 500   |      | $\text{V}/\mu\text{s}$ |
| $t_q$    | Turn-Off Time                              | $I_T=2\text{A}$ , $T_p=50\mu\text{s}$ , $dv/dt=5\text{V}/\mu\text{s}$ ,<br>$di/dt=-30\text{A}/\mu\text{s}$ |       | 35   | $\mu\text{s}$          |
| $t_{gt}$ | Turn-On Time                               | $I_G = 150\text{mA}$ , $PW = 15\ \mu\text{s}$ ,<br>$I_T = 130\text{A(pk)}$                                 |       | 3    | $\mu\text{s}$          |

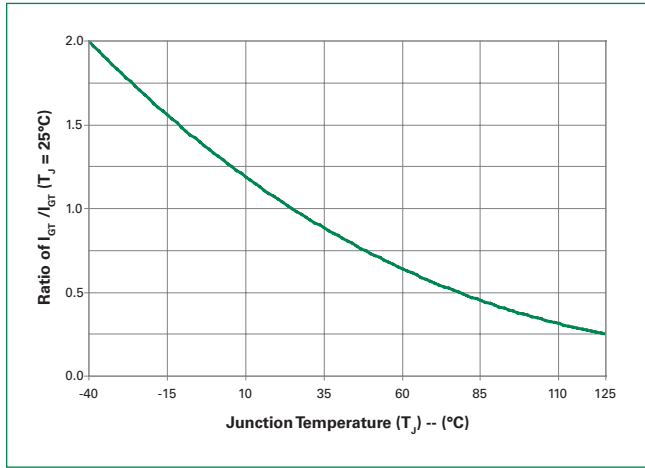
### Static Characteristics

| Symbol                 | Parameter               | Test Conditions                                   | Value | Unit |               |
|------------------------|-------------------------|---|-------|------|---------------|
| $V_{TM}$               | Peak On-State Voltage   | $I_T = 130\ \text{A Peak}$ , $T_p=380\mu\text{s}$ | MAX.  | 1.8  | V             |
| $I_{DRM}$<br>$I_{RRM}$ | $V_D = V_{DRM}/V_{RRM}$ | $T_J = 25^\circ\text{C}$                          | MAX.  | 20   | $\mu\text{A}$ |
|                        |                         | $T_J = 125^\circ\text{C}$                         |       | 3000 | $\mu\text{A}$ |

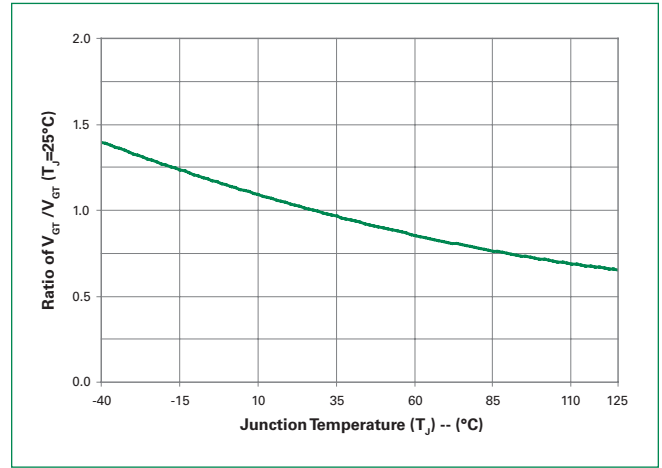
### Thermal Resistances

| Symbol            | Parameter                            | Value | Unit                      |
|-------------------|--------------------------------------|-------|---------------------------|
| $R_{\theta(J-C)}$ | Thermal Resistance, Junction to Case | 0.3   | $^\circ\text{C}/\text{W}$ |

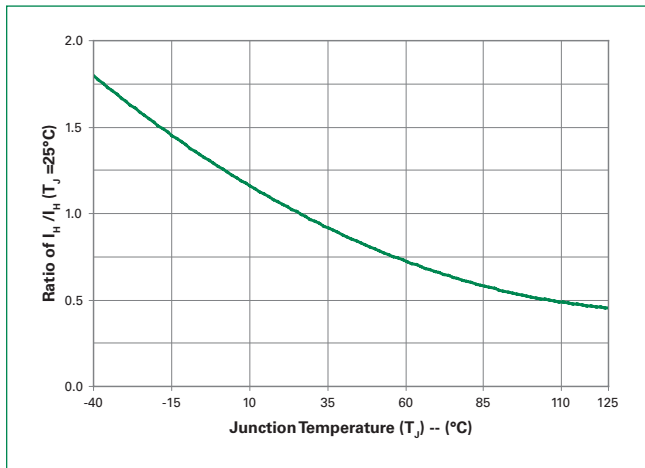
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



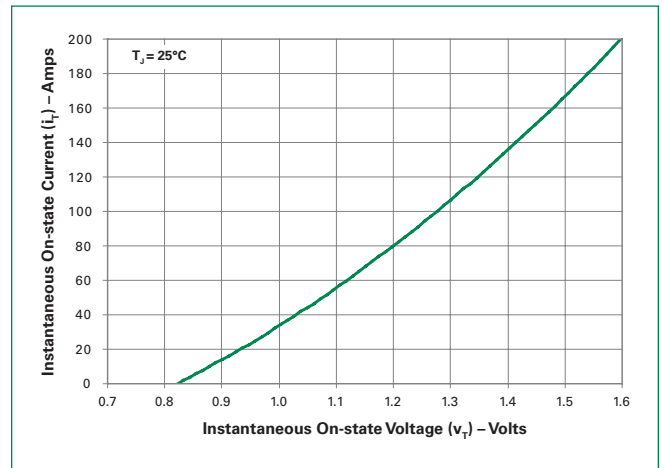
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



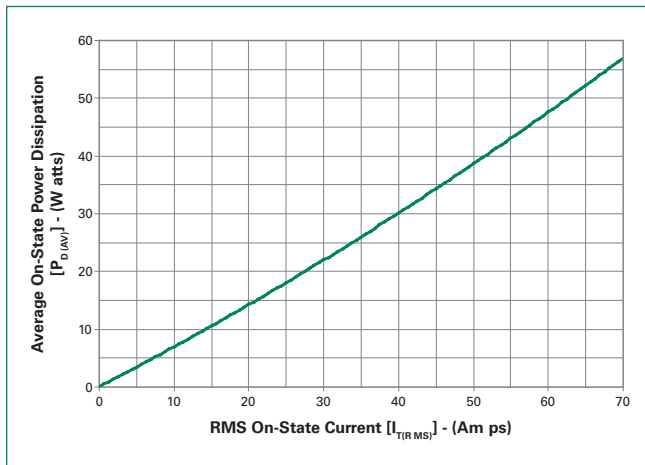
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



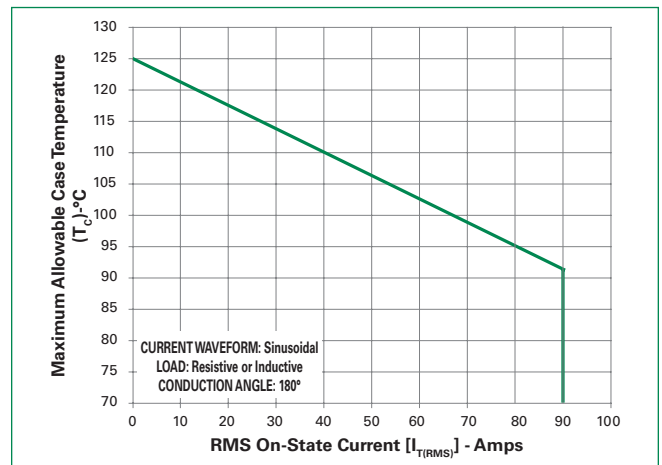
**Figure 4: On-State Current vs. On-State Voltage (Typical, per SCR)**



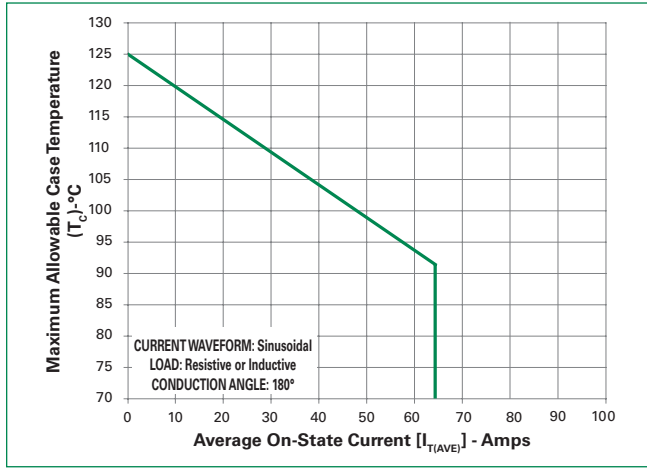
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current per SCR**



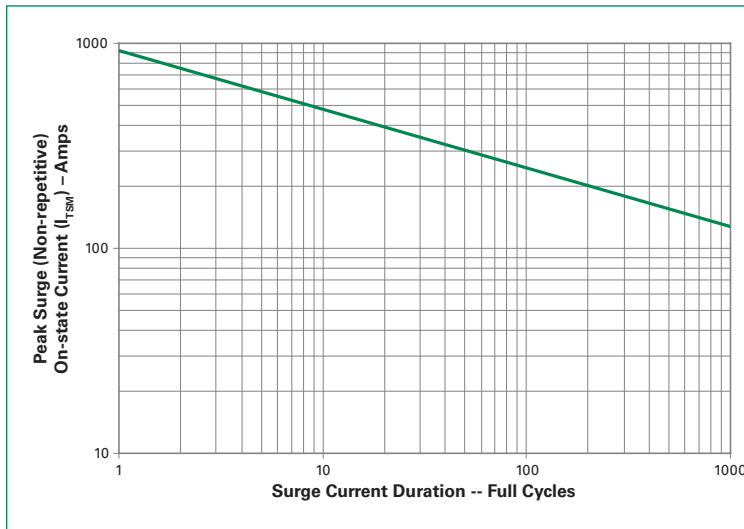
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current per module**



**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current per module**



**Figure 7: Surge Peak On-State Current vs. Number of Cycles**



SUPPLY FREQUENCY: 60 Hz Sinusoidal  
 LOAD: Resistive  
 RMS On-State Current [ $I_{T(RMS)}$ ]: Maximum Rated Value at Specified Case Temperature

- Notes:
1. Gate control may be lost during and immediately following surge current interval.
  2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

**Physical Specifications**

|                        |   |
|------------------------|---|
| <b>Terminal Finish</b> | 100% Nickel Plated  |
| <b>Body</b>            | UL recognized epoxy meeting flammability classification 94V-0 |
| <b>Lead Material</b>   | Copper Alloy  |

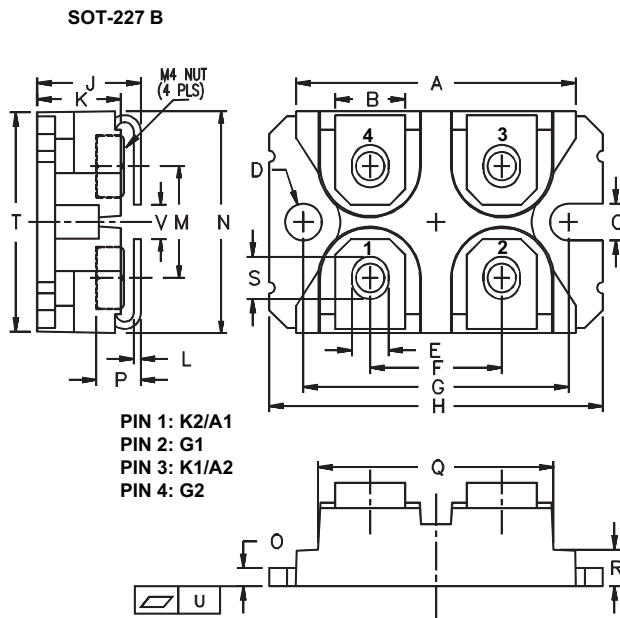
**Design Considerations**

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

**Environmental Specifications**

| Test                                 | Specifications and Conditions   |
|--------------------------------------|---|
| <b>AC Blocking</b>                   | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours  |
| <b>Intermittent Operational Life</b> | MIL-STD-750, Method 1037, 15000cycles, $\Delta T_J \geq 100^\circ\text{C}$  |
| <b>Temperature/Humidity</b>          | EIA / JEDEC, JESD22-A101<br>504 hours; 160V - DC: 85°C;<br>85% rel humidity |
| <b>High Temp Storage</b>             | MIL-STD-750, M-1031,<br>1008 hours; 150°C                                   |
| <b>Low-Temp Storage</b>              | 1008 hours; -40°C   |
| <b>Temperature Cycling</b>           | MIL-STD-750, M-1051,<br>20 cycles; -25°C to +125°C; 15-min dwell-time       |

**Dimensions**



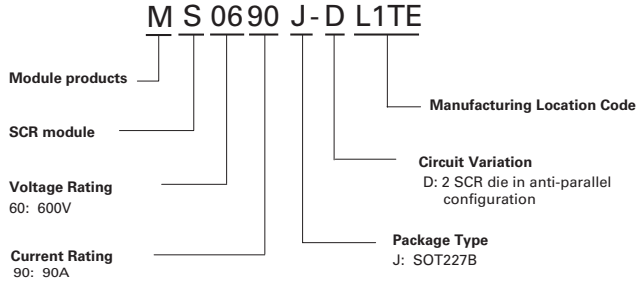
Note: M4x7.5MM screw, 4 screws per unit.

| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 1.240  | 1.256 | 31.50       | 31.90 |
| B         | 0.307  | 0.323 | 7.80        | 8.20  |
| C         | 0.161  | 0.169 | 4.09        | 4.29  |
| D         | 0.161  | 0.169 | 4.09        | 4.29  |
| E         | 0.161  | 0.169 | 4.09        | 4.29  |
| F         | 0.587  | 0.595 | 14.91       | 15.11 |
| G         | 1.186  | 1.193 | 30.12       | 30.30 |
| H         | 1.489  | 1.505 | 37.80       | 38.20 |
| J         | 0.460  | 0.481 | 11.68       | 12.22 |
| K         | 0.351  | 0.378 | 8.92        | 9.60  |
| L         | 0.030  | 0.033 | 0.76        | 0.84  |
| M         | 0.497  | 0.507 | 12.62       | 12.88 |
| N         | 0.990  | 1.001 | 25.15       | 25.42 |
| O         | 0.078  | 0.084 | 1.98        | 2.13  |
| P         | 0.193  | 0.232 | 4.90        | 5.89  |
| Q         | 1.045  | 1.059 | 26.54       | 26.90 |
| R         | 0.155  | 0.174 | 3.94        | 4.42  |
| S         | 0.186  | 0.191 | 4.72        | 4.85  |
| T         | 0.968  | 0.987 | 24.50       | 25.07 |
| U         | 0      | 0.005 | 0           | 0.127 |
| V         | 0.130  | 0.180 | 3.30        | 4.57  |

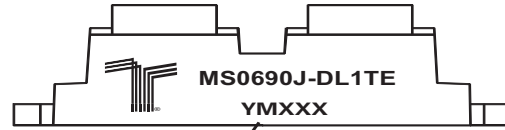
**Packing Options**

| Part Number   | Weight | Packing Mode | Base Quantity |
|---------------|--------|--------------|---------------|
| MS0690J-DL1TE | 30g    | Tube         | 160           |

**Part Numbering System**



**Part Marking System**



Date Code Marking  
 Y: Year Code  
 M: Month Code  
 XXX: Lot Trace Code